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Inclosure Material:

Metal

**Overall Length:** 

0.297 inches

# **Overall Diameter:**

0.620 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Unthreaded hole

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

**Current Rating Per Characteristic:** 

Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release5109 professional/industrial association specification

Shelf Life:

N/a

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Unit Of Measure:
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## Demilitarization:

No

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